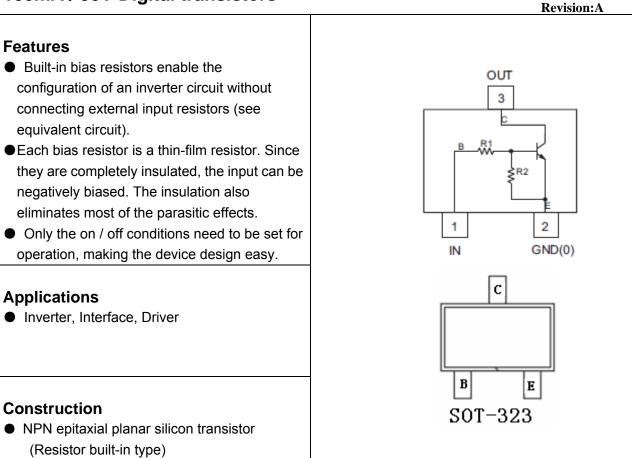
### SHANGHAI SINO-IC MICROELECTRONICS CO., LTD.

#### SEC113ZU

### 100mA / 50V Digital transistors



#### Absolute maximum ratings (Ta=25°C)

Parameter		Symbol		Limits		Unit		
			-					•
Supply voltage		V <sub>CC</sub>		50			V	
Input voltage		V <sub>IN</sub>		-5 to +10			V	
Output current		Ι <sub>ο</sub>		100			mA	
		I <sub>C(MAX)</sub>		100				
Power dissipation		PD		200			mW	
Junction temperature			TJ		150		°C	
Storage temperature		T <sub>stg</sub>		-55 to +150			°C	
THERMAL CHARACTERISTIC	S							
Thermal Resistance, Junction-to-Ambient (Note 2)			R <sub>eja</sub> 625		625	°C/W		N
Electrical characteristics (Ta=	<b>25℃)</b>			•		·		
Parameter	Syml	bol	Condition	ns	Min	Тур.	Max.	Unit
	V <sub>I(off)</sub>		V <sub>CC</sub> =5V, I <sub>O</sub> =100∪A		0.3	-	-	
Input voltage	V <sub>I(o</sub>	n)	V <sub>0</sub> =0.3V, I <sub>0</sub> =20mA		_	-	3	V

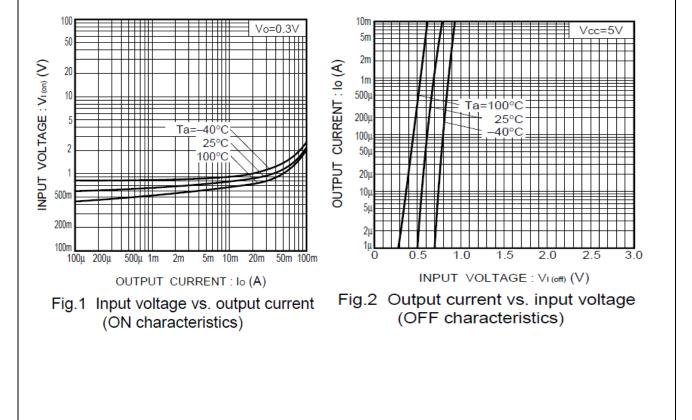
June 2006

# SEC113ZU

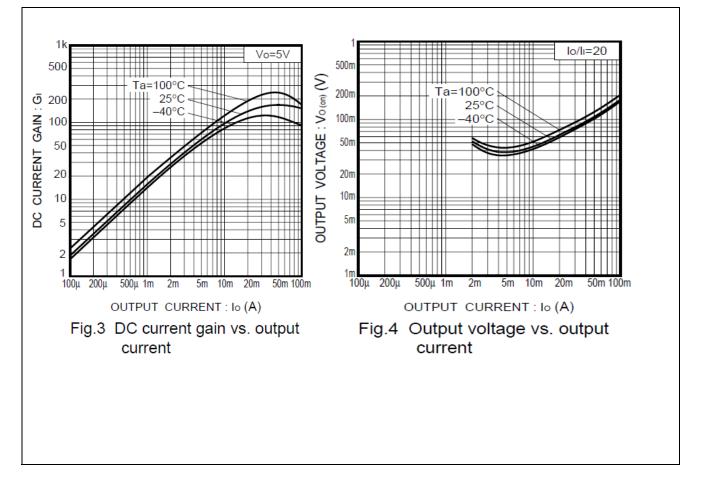
VO(on)	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA	-	0.1	0.3	V
I	V <sub>I</sub> =5V	-	-	7.2	mA
I <sub>O(off)</sub>	V <sub>CC</sub> =50V, V <sub>I</sub> =0V	-	-	0.5	μA
Gı	V <sub>0</sub> =5V, I <sub>0</sub> =5mA	33	-	-	-
R <sub>1</sub>		0.7	1	1.3	KΩ
R <sub>2/</sub> R <sub>1</sub>	-	8	10	12	-
f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>E</sub> =–5mA, f=100MHz	-	250	-	MHz
	$I_{I}$ $I_{O(off)}$ $G_{I}$ $R_{1}$ $R_{2/R_{1}}$	$\begin{tabular}{ c c c c c } \hline I_{I} & V_{I}=5V \\ \hline I_{O(off)} & V_{CC}=50V, V_{I}=0V \\ \hline G_{I} & V_{O}=5V, I_{O}=5mA \\ \hline R_{1} & \hline \\ \hline R_{2}/R_{1} & \hline \\ f_{T} & V_{CE}=10V, I_{E}=-5mA, \\ \hline \end{tabular}$	$\begin{array}{c c} I_{1} & V_{I}=5V & -\\ I_{O(off)} & V_{CC}=50V, V_{I}=0V & -\\ G_{I} & V_{O}=5V, I_{O}=5mA & 33\\ \hline R_{1} & 0.7\\ \hline R_{2/R_{1}} & - & 8\\ \hline f_{T} & V_{CE}=10V, I_{E}=-5mA, & -\\ \end{array}$	I       V <sub>I</sub> =5V       -       0.1         I       V <sub>I</sub> =5V       -       -         IO(off)       V <sub>CC</sub> =50V, V <sub>I</sub> =0V       -       -         GI       V <sub>O</sub> =5V, I <sub>O</sub> =5mA       33       -         R1       0.7       1         R2/R1       -       8       10         fT       V <sub>CE</sub> =10V, I <sub>E</sub> =-5mA,       -       250	Image: Normal and the second secon

\*Characteristics of built-in transistor

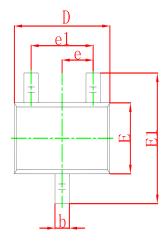


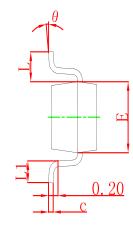


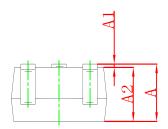
# SEC113ZU



# SOT-323 Suggested Pad Layout







Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	in Max Min	Max			
А	0.900	1.100	0.035	0.043		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.000	0.035	0.039		
b	0.200	0.400	0.008	0.016		
С	0.080	0.150	0.003	0.006		
D	2.000	2.200	0.079	0.087		
E	1.150	1.350	0.045	0.053		
E1	2.150	2.450	0.085	0.096		
е	0.650	) TYP	0.026 TYP			
e1	1.200	1.400	0.047	0.055		
L	0.525	5 REF	0.021 REF			
L1	0.260	0.460	0.010	0.018		
θ	0°	8°	0°	8°		

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